
ATMEL Wireless & Microcontrollers

Varaktormodellierung

Bipolar-Arbeitskreis

26.10.2001

Frankfurt/Oder

Gliederung

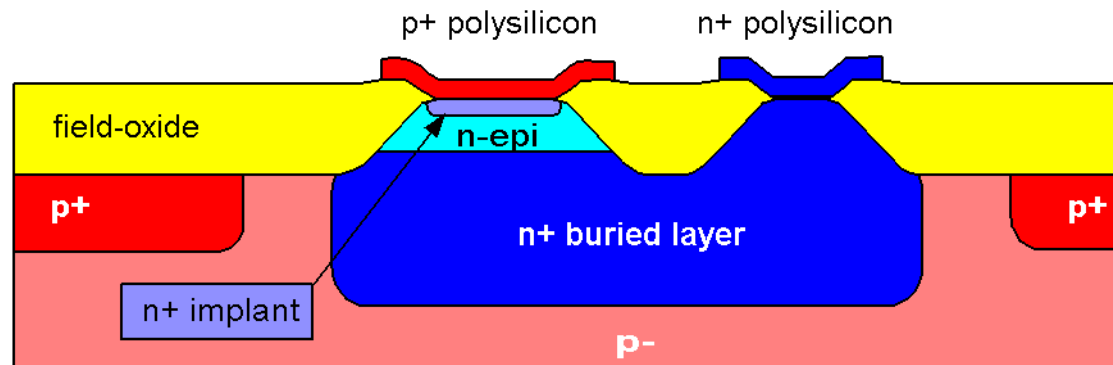
- Anforderungen
- Realisierung
- Approximation der C(U)-Kennlinie
- Ersatzschaltung
- Ergebnis
- Implementierung

Anforderungen

- **ausreichender normierter Kapazitätshub**
- **Soll-Kennlinienverlauf**
- **laterale Skalierbarkeit**
- **Deaktivierung von nicht angeschlossenen Streifen (“spare parts”)**
- **Implementierung für ELDO, HPEESOFsim, SPECTRE**
- **Unterstützung worst-case Simulation**

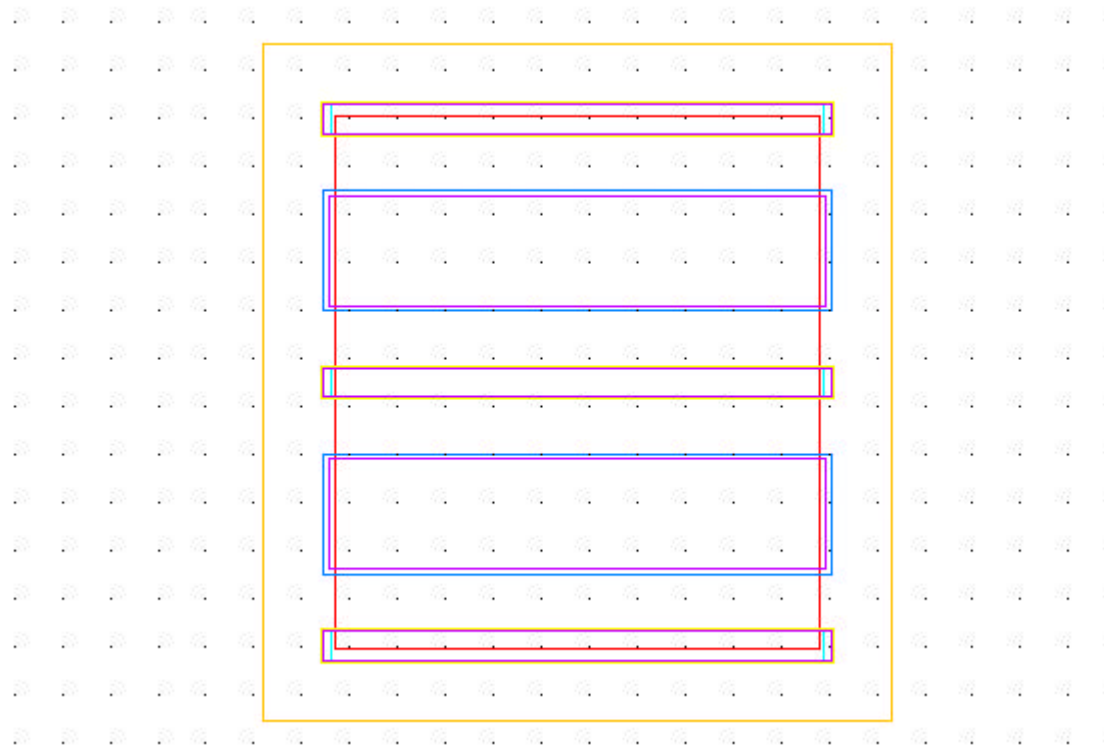
Realisierung

- zusätzliche As-Implantation (Prozeßopotion)
- Querschnitt



Parameter : Länge, Weite, Anzahl Streifen, Anzahl nicht angeschlossener Streifen

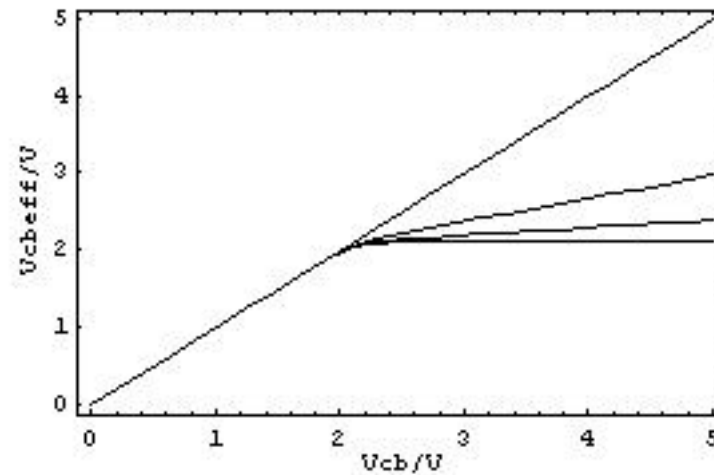
Layout:



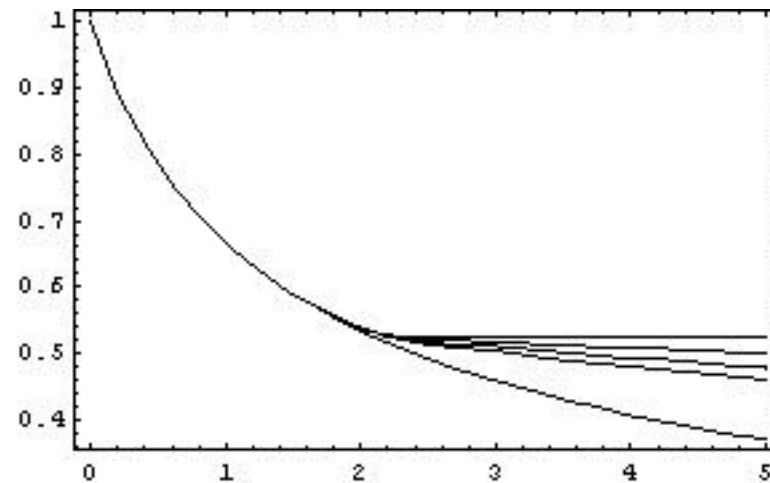
Kennlinienapproximation: Vcbeff

```
minlogexp[x_, x0_, eps_] := Module[
  {y},
  y = Min[x, x0] - Abs[eps] Log[1 + Exp[-Abs[(x - x0) / eps]]];
  Return[y]
]
vcbeff[v_, vclip_, eps_, slope_] := Module[{vcb1, y},
  vcb1 = vclip + slope * (v - vclip);
  y = minlogexp[v, vcb1, eps];
  Return[y];
]
```

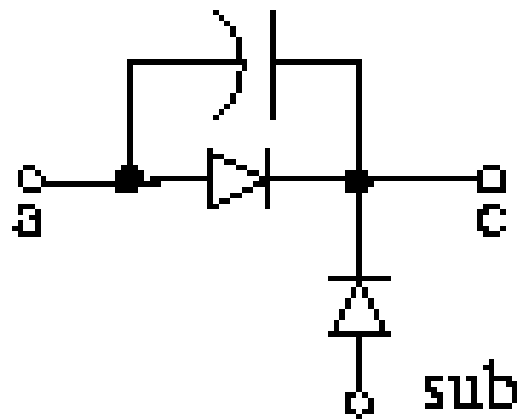
Kennlinienapproximation: V_{cbeff}



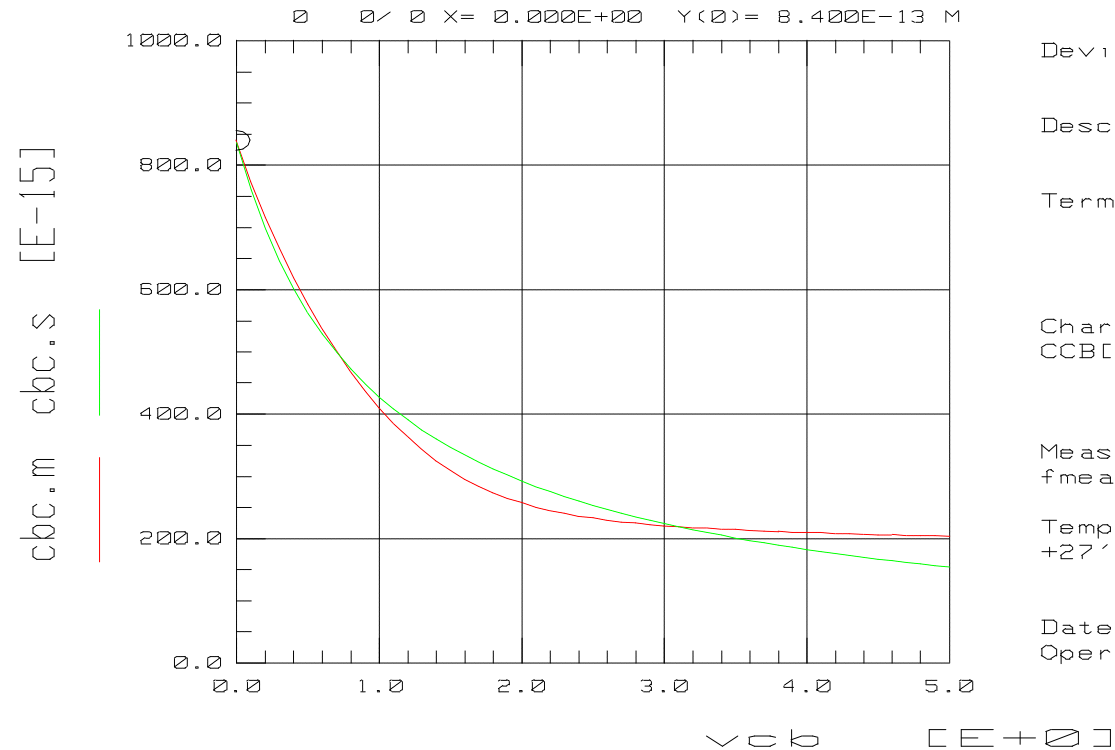
Kennlinienapproximation: V_{cbeff}



Ersatzschaltung



Resultat: Standarddiodenmodell



Device: BC Varactor

Description: DCPMNI2_2YX
2x(10x42.2) μ

Terminals: (a, c, sub)

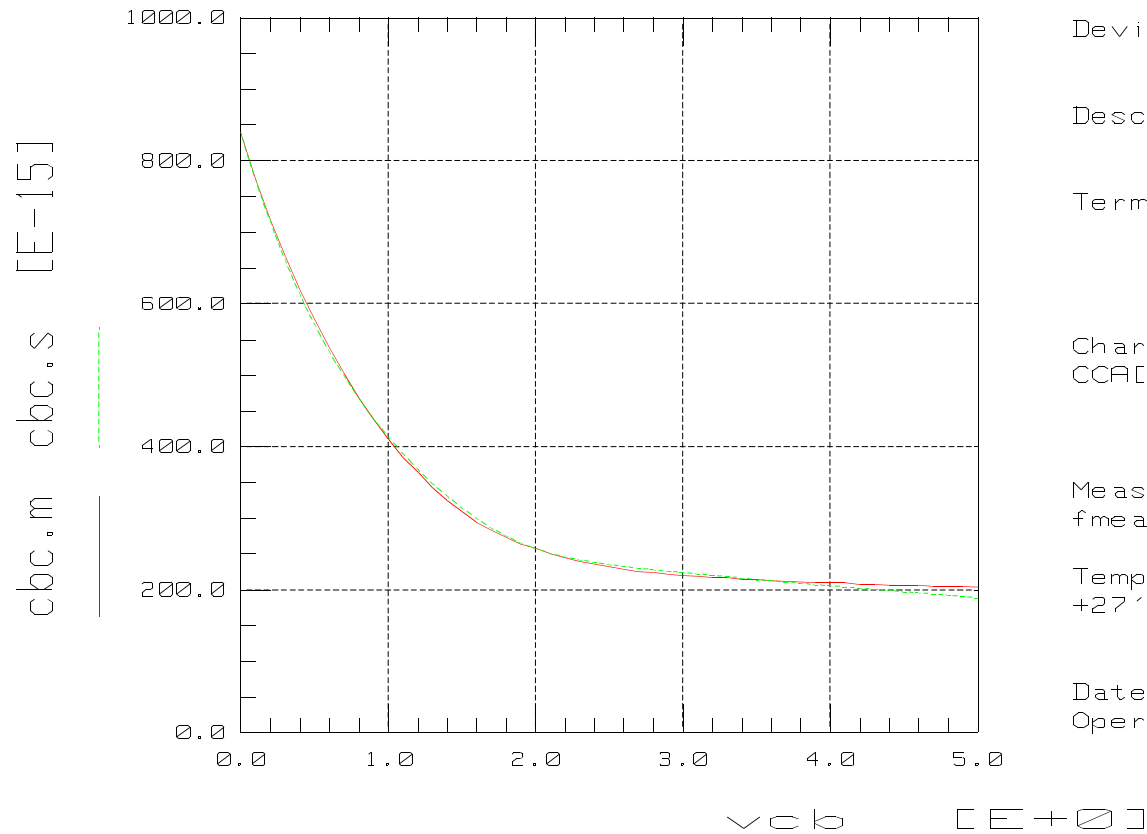
Characteristics:
CCB[F] versus VSUBI[V]

Measurement Conditions:
fmeas=1MHz, vc=0-5V, vb,v

Temperature:
+27°C

Date: 10/17/01
Operator: B.Kraus

Resultat: verbessertes Modell



Device: BC Varactor Diode

Description: DCPMNI2_2YX
2x(10x42.2)um2

Terminals: (a, c, sub)

Characteristics:
CCA[F] versus VC[V]

Measurement Conditions:
fmeas=1MHz, vc=0-5V, va,vsub=0V

Temperature:
+27°C

Date: 07/19/01
Operator: B.Kraus

;* Simulation model: Scalable Macro Model (anode=a, cathode=c, substrate=sub, n=number of stripes, nnu=number of not used stripes)

;* Simulator: HPEESOF SIM v150 rev. 204

define DCPMNI21 (a c sub)

parameters \

W=5u L=21.2u N=2 NNU=0

.
. .
.

NEFF=max(1,N-NNU)

SDD:SDDNP2 a b f 0 I[1,0]=-_i2*c_v F[2,0]=_v1-_v2

C:CC f 0 C=CACA+CACP

vcb1=VCLIP+slope*(_v1-VCLIP)

vcbeff=max(_v1,vcb1)+abs(E)*ln(1+exp(-abs(_v1-vcb1)/E))

c_v=(1-vcbeff/VD)^-M

ELDO:

GC a b value = $\{ (1 - (\text{dmax}(V_{CLIP} + \text{slope} * (V(a,b) - V_{CLIP}), V(a,b)) + \text{abs}(E) * \log(1 + \exp(-\text{abs}(V_{CLIP} + \text{slope} * (V(a,b) - V_{CLIP}) - V(a,b)) / E))) / V_D)^{-M} * I(V_{MC}) \}$

SPECTRE:

CCB (a b e f) hccs4varactor_hdl

```
'include "discipline.h"  
'include "constants.h"  
//-----  
// hccs4varactor_hdl  
//  
// - hybrid (voltage & current) controlled current source  
// for voltage dependent capacitance  
// CAS, May 1990, p. 9-11  
analog begin  
    v = V(iout_p, iout_n);  
    vcb1 = vclip+slope*(v-vclip);  
    vcbeff=max(v,vcb1)+abs(eps)*ln(1+exp(-abs((v-vcb1)/eps)));  
    c_v=pow((1-vcbeff/vd),(-m));  
    I(iout_p, iout_n) <+ c_v*I(iin_p, iin_n);  
end  
endmodule
```